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October 2014

## 2N3904 / MMBT3904 / PZT3904 NPN General-Purpose Amplifier

### Description

This device is designed as a general-purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.



### Ordering Information

Part Number	Marking	Package	Packing Method	Pack Quantity
2N3904BU	2N3904	TO-92 3L	Bulk	10000
2N3904TA	2N3904	TO-92 3L	Ammo	2000
2N3904TAR	2N3904	TO-92 3L	Ammo	2000
2N3904TF	2N3904	TO-92 3L	Tape and Reel	2000
2N3904TFR	2N3904	TO-92 3L	Tape and Reel	2000
MMBT3904	1A	SOT-23 3L	Tape and Reel	3000
PZT3904	3904	SOT-223 4L	Tape and Reel	2500

2N3904 / MMBT3904 / PZT3904 — NPN General-Purpose Amplifier

## Absolute Maximum Ratings<sup>(1), (2)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$V_{CEO}$	Collector-Emitter Voltage	40	V
$V_{CBO}$	Collector-Base Voltage	60	V
$V_{EBO}$	Emitter-Base Voltage	6.0	V
$I_C$	Collector Current - Continuous	200	mA
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to 150	$^\circ\text{C}$

### Notes:

1. These ratings are based on a maximum junction temperature of  $150^\circ\text{C}$ .
2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

## Thermal Characteristics

Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Maximum			Unit
		2N3904	MMBT3904 <sup>(3)</sup>	PZT3904 <sup>(4)</sup>	
$P_D$	Total Device Dissipation	625	350	1,000	mW
	Derate Above $25^\circ\text{C}$	5.0	2.8	8.0	$\text{mW}/^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	$^\circ\text{C}/\text{W}$

### Notes:

3. Device is mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.
4. Device is mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm, mounting pad for the collector lead minimum  $6\text{ cm}^2$ .

## Electrical Characteristics

Values are at  $T_A = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
<b>OFF CHARACTERISTICS</b>					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 1.0\text{ mA}, I_B = 0$	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10\text{ }\mu\text{A}, I_E = 0$	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10\text{ }\mu\text{A}, I_C = 0$	6.0		V
$I_{BL}$	Base Cut-Off Current	$V_{CE} = 30\text{ V}, V_{EB} = 3\text{ V}$		50	nA
$I_{CEX}$	Collector Cut-Off Current	$V_{CE} = 30\text{ V}, V_{EB} = 3\text{ V}$		50	nA
<b>ON CHARACTERISTICS<sup>(5)</sup></b>					
$h_{FE}$	DC Current Gain	$I_C = 0.1\text{ mA}, V_{CE} = 1.0\text{ V}$	40		
		$I_C = 1.0\text{ mA}, V_{CE} = 1.0\text{ V}$	70		
		$I_C = 10\text{ mA}, V_{CE} = 1.0\text{ V}$	100	300	
		$I_C = 50\text{ mA}, V_{CE} = 1.0\text{ V}$	60		
		$I_C = 100\text{ mA}, V_{CE} = 1.0\text{ V}$	30		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 10\text{ mA}, I_B = 1.0\text{ mA}$		0.2	V
		$I_C = 50\text{ mA}, I_B = 5.0\text{ mA}$		0.3	
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 10\text{ mA}, I_B = 1.0\text{ mA}$	0.65	0.85	V
		$I_C = 50\text{ mA}, I_B = 5.0\text{ mA}$		0.95	
<b>SMALL SIGNAL CHARACTERISTICS</b>					
$f_T$	Current Gain - Bandwidth Product	$I_C = 10\text{ mA}, V_{CE} = 20\text{ V},$ $f = 100\text{ MHz}$	300		MHz
$C_{obo}$	Output Capacitance	$V_{CB} = 5.0\text{ V}, I_E = 0,$ $f = 100\text{ kHz}$		4.0	pF
$C_{ibo}$	Input Capacitance	$V_{EB} = 0.5\text{ V}, I_C = 0,$ $f = 100\text{ kHz}$		8.0	pF
NF	Noise Figure	$I_C = 100\text{ }\mu\text{A}, V_{CE} = 5.0\text{ V},$ $R_S = 1.0\text{ k}\Omega,$ $f = 10\text{ Hz to }15.7\text{ kHz}$		5.0	dB
<b>SWITCHING CHARACTERISTICS</b>					
$t_d$	Delay Time	$V_{CC} = 3.0\text{ V}, V_{BE} = 0.5\text{ V}$		35	ns
$t_r$	Rise Time	$I_C = 10\text{ mA}, I_{B1} = 1.0\text{ mA}$		35	ns
$t_s$	Storage Time	$V_{CC} = 3.0\text{ V}, I_C = 10\text{ mA},$		200	ns
$t_f$	Fall Time	$I_{B1} = I_{B2} = 1.0\text{ mA}$		50	ns

**Note:**

5. Pulse test: pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2.0\%$ .

## Typical Performance Characteristics



Figure 1. Typical Pulsed Current Gain vs. Collector Current



Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

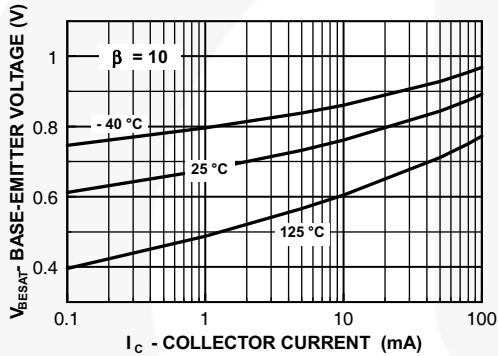


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current



Figure 4. Base-Emitter On Voltage vs. Collector Current

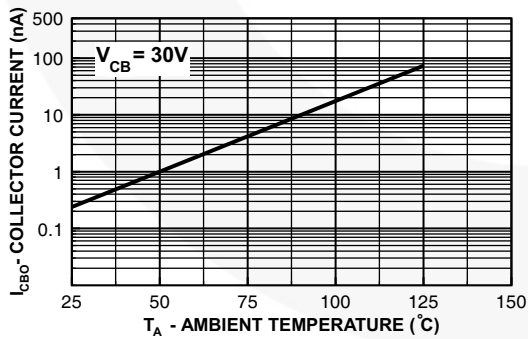


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

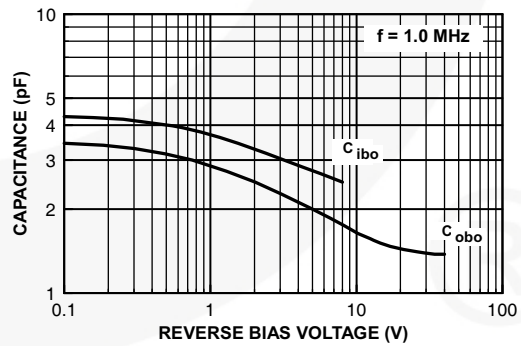
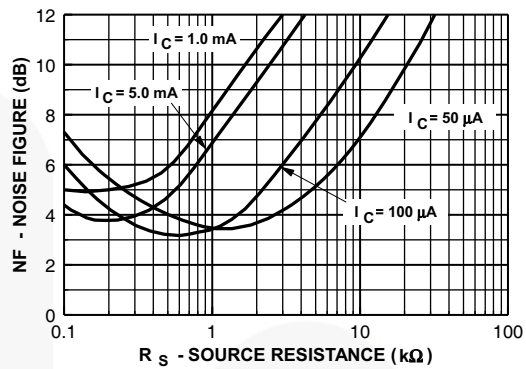


Figure 6. Capacitance vs. Reverse Bias Voltage

**Typical Performance Characteristics (Continued)**



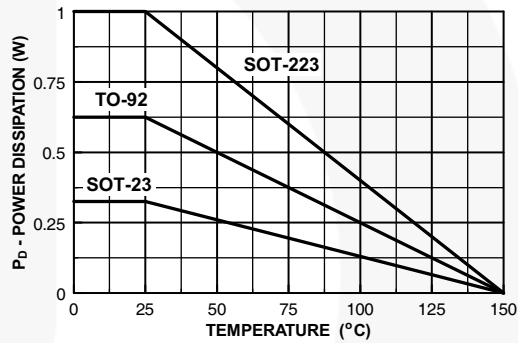
**Figure 7. Noise Figure vs. Frequency**



**Figure 8. Noise Figure vs. Source Resistance**



**Figure 9. Current Gain and Phase Angle vs. Frequency**



**Figure 10. Power Dissipation vs. Ambient Temperature**



**Figure 11. Turn-On Time vs. Collector Current**



**Figure 12. Rise Time vs. Collector Current**

Typical Performance Characteristics (Continued)

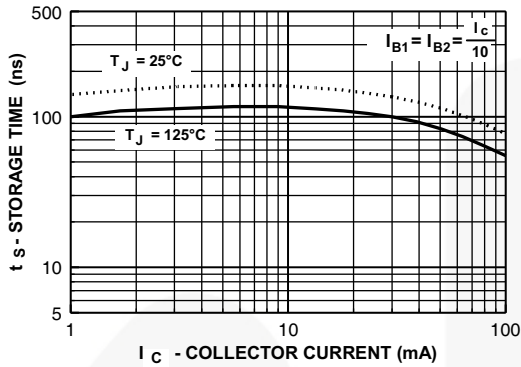


Figure 13. Storage Time vs. Collector Current



Figure 14. Fall Time vs. Collector Current



Figure 15. Current Gain

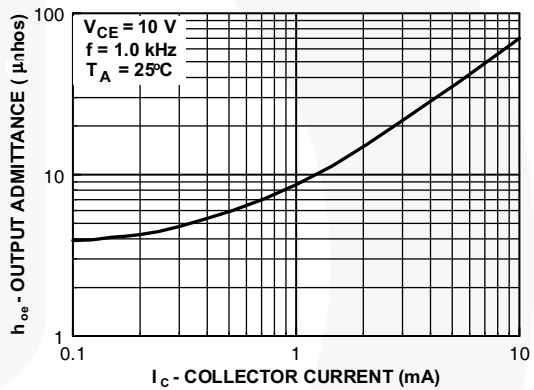


Figure 16. Output Admittance

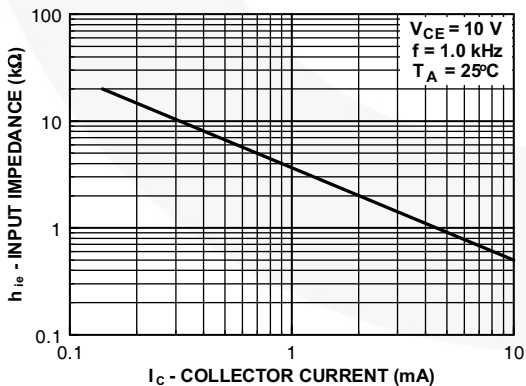


Figure 17. Input Impedance



Figure 18. Voltage Feedback Ratio

Test Circuits

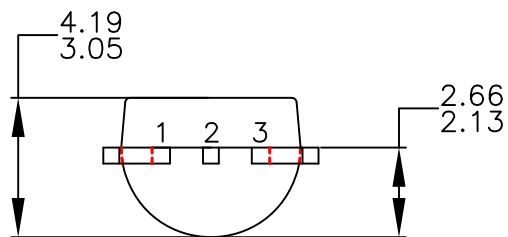
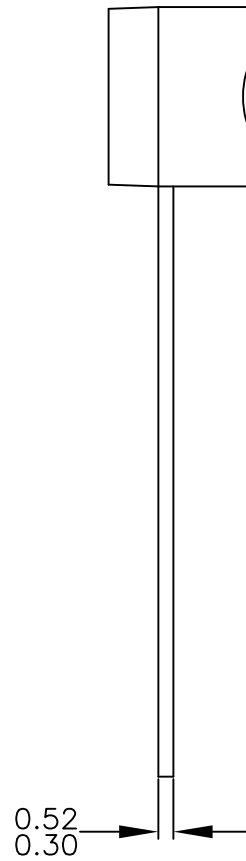
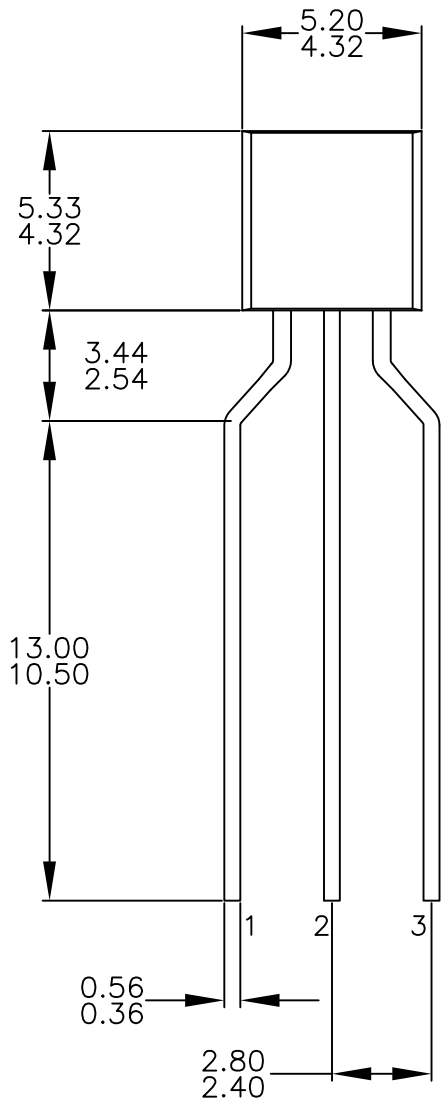


Figure 19. Delay and Rise Time Equivalent Test Circuit



Figure 20. Storage and Fall Time Equivalent Test Circuit



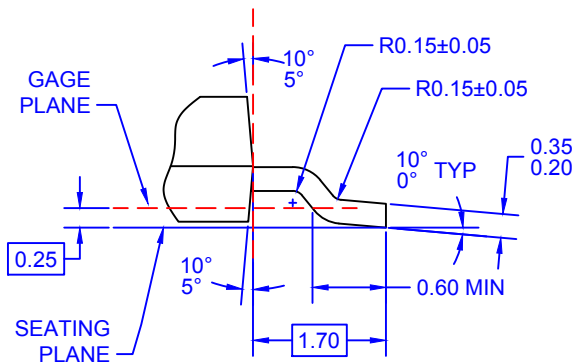
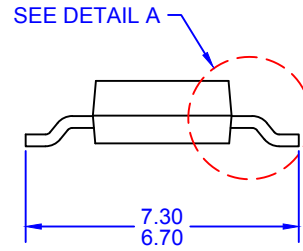


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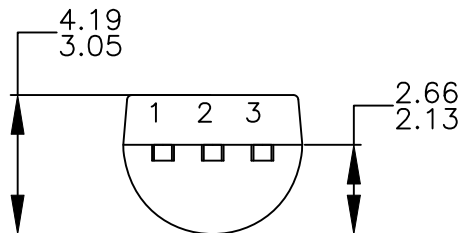
LAND PATTERN RECOMMENDATION



DETAIL A  
SCALE: 2:1

- NOTES: UNLESS OTHERWISE SPECIFIED  
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 C) DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH. MOLD FLASH OR BURRS DOES NOT EXCEED 0.10MM.  
 D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-2009.  
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SEE DETAIL A



**DETAIL A**  
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- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.
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